ABSOLUTE MAXIMUM RATINGS

+0.3V to +4.3V
0.3V to (V _{CC} + 0.3V)
1V peak
+5dBm
±10mA
°C)
$T_A = +70^{\circ}C)2W$

Operating Temperature Range	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

 $(V_{CC} = +2.7V \text{ to } +3.3V, R_{RBIAS} = R_{RLNA} = 24k\Omega$, BUFFEN = LOW, all RF and IF outputs connected to V_{CC} , no RF applied, $T_A = -40^{\circ}C$ to +85°C. Typical values are at +3.0V and $T_A = +25^{\circ}C$, unless otherwise noted. Refer to Operational Modes table for control logic.)

PARAMETER	CON	MIN	ТҮР	МАХ	UNITS			
PCS CDMA MODES								
Operating Supply Current	High-gain, low-linearity mod	de		18	24	m 4		
Operating Supply Current	High-gain, high-linearity mo	ode		25	33	ШA		
CELLULAR CDMA MODE								
	Low-gain mode			19.5	25			
Operating Supply Current	High-gain, low-linearity mod	de		18	24	mA		
	High-gain, high-linearity mo	ode		28	35			
FM MODE								
Operating Supply Current				13.5	17	mA		
SHUTDOWN MODE								
Shutdown Supply Current				0.1	5	μA		
ALL MODES								
		LO/2 = LOW		7.2	9.5	m۸		
LO Buller Supply Culterit	BUFFEN = HIGH	LO/2 = HIGH		10.3		ША		
Additional Operational Current Divider Active	Cellular and FM mode; LO/		1.2		mA			
Digital Input Logic High			2.0			V		
Digital Input Logic Low					0.6	V		
Digital Input High Current					5	μA		
Digital Input Low Current			-25			μA		

AC ELECTRICAL CHARACTERISTICS

(MAX2338 EV kit, V_{CC} = +2.7V to +3.3V, f_{PLNAIN} = f_{PMIXIN} = 1930MHz to 1990MHz, f_{CLNAIN} = f_{CMIXIN} = 869MHz to 894MHz, f_{IF} = 183MHz, high side LO, LO/2 = LOW. All ports matched to 50 Ω , R_{RLNA} = R_{RBIAS} = 24k Ω , T_A = -40°C to +85°C. Typical values are at T_A = +25°C, V_{CC} = +3.0V, unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS				
OVERALL PERFORMANCE									
Low-Band RF Frequency Range		869		894	MHz				
High-Band RF Frequency Range		1930		1990	MHz				
Low-Band LO Frequency Range	After divider if active (Note 1)	950		1100	MHz				
High-Band LO Frequency Range	(Note 1)	1750		2210	MHz				
IF Frequency Range	(Note 1)	80		220	MHz				
LO Input Level		-7	-3	0	dBm				
CELLULAR LNA PERFORMANCE									
HIGH-GAIN, HIGH-LINEARITY MOD	ES								
Gain (Note 2)		14.0	15.7	17.0	dB				
Noise Figure (Note 3)	$T_A = +25^{\circ}C$		1.4	1.6	dB				
Noise Figure Change Due to Temperature	$T_A = +25^{\circ}C$ to T_{MAX}		0.3		dB				
IIP3 (Notes 3, 4)		9.5	12		dBm				
CDMA HIGH-GAIN, LOW-LINEARITY	MODE AND FM MODE	•							
Gain (Note 2)		13	14.7	16.5	dB				
Noise Figure (Note 3)	$T_A = +25^{\circ}C$		1.4	1.7	dB				
IIP3 (Note 3, 4)		2.5	5.5		dBm				
CDMA LOW-GAIN MODE		•							
Gain (Note 2)		-4.0	-2.3	0	dBm				
Noise Figure (Note 3)			5	6	dB				
IIP3 (Notes 3, 4)		15	18		dBm				
PCS LNA PERFORMANCE									
CDMA HIGH-GAIN, HIGH-LINEARIT	YMODE								
Gain (Note 2)		13.8	15.3	16.9	dB				
Noise Figure (Note 3)	$T_A = +25^{\circ}C$		1.4	1.7	dB				
Noise Figure Change Due to Temperature	$T_A = +25^{\circ}C$ to T_{MAX}		0.3		dB				
IIP3 (Notes 3, 5)		5.0	7.7		dBm				
CDMA HIGH-GAIN, LOW-LINEARITY	/ MODE	·							
Gain (Note 2)		13.0	14.5	16.5	dB				
Noise Figure (Note 3)	$T_A = +25^{\circ}C$		1.4	1.7	dB				
IIP3 (Notes 3, 5)		2.5	7.5		dBm				
CELLULAR MIXER PERFORMANCE									
CDMA HIGH-GAIN, HIGH-LINEARIT	Y, AND LOW-GAIN MODES								
Gain (Note 2)		10.3	13.3	16.4	dB				
Noise Figure (Note 3)	$T_A = +25^{\circ}C$		7.8	9.0	dB				
IIP3 (Note 4)		3.0	5.5		dBm				



AC ELECTRICAL CHARACTERISTICS (continued)

(MAX2338 EV kit, V_{CC} = +2.7V to +3.3V, f_{PLNAIN} = f_{PMIXIN} = 1930MHz to 1990MHz, f_{CLNAIN} = f_{CMIXIN} = 869MHz to 894MHz, f_{IF} = 183MHz, high side LO, LO/2 = LOW. All ports matched to 50Ω , R_{RLNA} = R_{RBIAS} = 24k Ω , T_A = -40°C to +85°C. Typical values are at T_A = +25°C, V_{CC} = +3.0V, unless otherwise noted.)

PARAMETER		MIN	ТҮР	МАХ	UNITS				
HIGH-GAIN, LOW-LINEARITY IDLE MODE									
Gain (Note 2)			10.1	13	16	dB			
Noise Figure (Note 3)	$T_A = +25^{\circ}C$		7.3	9.0	dB				
IIP3 (Notes 3, 4)			1.4	3.5		dBm			
FM MODE									
Gain (Note 2)			6.0	8.8	11.1	dB			
Noise Figure (Note 3)	$T_A = +25^{\circ}C$			8.7	11.0	dB			
IIP3 (Note 4)			1.4	3.4		dBm			
PCS MIXER PERFORMANCE									
CDMA HIGH-GAIN, HIGH-LINEARIT	Y MODE								
Gain (Note 2)			11.7	14.5	17	dB			
Noise Figure (Note 3)	$T_A = +25^{\circ}C$			7.8	9.0	dB			
IIP3 (Notes 3, 5)		3.5	7.5		dBm				
HIGH-GAIN, LOW-LINEARITY MODE	E								
Gain (Note 2)			11.2	14	16.2	dB			
Noise Figure (Note 3)	T _A = +25°C		7.2	9.0	dB				
IIP3 (Note 5)			0.5	2.5		dBm			
ALL MODES									
Mixer Output 1dB Compression				-1		dBm			
4 x 5 Suppression (Note 6)				>45		dB			
2 x 2 Input Intercept Point (Notes 3, 7)			25	33		dBm			
LO Output Level (Note 3)	Into 50Ω or 100Ω lo	ad, BUFFEN = HIGH	-12	-6		dBm			
LO Output Leakage	BUFFEN = LOW			-35		dBm			
LO Emission at PCS LNA Input Port			-55		dBm				
LO Emission at Cellular LNA Input Port				-55		dBm			
LO Output Harmonic Suppression	BUFFEN = HIGH			-15		dBc			
	PCS band, 80MHz below LO			-161		dDm/Ll=			
	DUFFEIN = HIGH	Cellular band, 45MHz below LO	-161		uBIII/HZ				
RF Ports Return Loss	All active RF ports in		10		dB				

Note 1: Operation over this frequency range may require the ports to be rematched for the desired operating frequency.

Note 2: MIN guaranteed by production test, MAX guaranteed by design and characterization.

Note 3: Guaranteed by design and device characterization.

Note 4: Two-tone IIP3. Tested at f_{RF1} = 880MHz, f_{RF2} = 880.9MHz, and power = -25dBm/tone.

Note 5: Two-tone IIP3. Tested at f_{RF1} = 1960MHz, f_{RF2} = 1961.25MHz, and power = -25dBm/tone.

Note 6: $F_{LO} = 1064MHZ$, $f_{RF1} = 887.8MHz$ at -30dBm, $f_{RF2} = 881MHz$ at -100dBm. Performance is measured as P_{IF} due to RF1 - P_{IF} due to RF2.

Note 7: $F_{LO} = 2143$ MHz, $f_{RF1} = 2051.5$ MHz at -35dBm, $f_{RF2} = 1960$ MHz at -100dBm. Performance is measured as P_{IF} due to RF1 - P_{IF} due to RF2.



Typical Operating Characteristics

$(T_A = +25^{\circ}C, unless otherwise noted.)$ **PCS-BAND HGHL LNA GAIN PCS-BAND SUPPLY CURRENT CELLULAR-BAND SUPPLY CURRENT** vs. CURRENT 30 30 17 $T_A = -40^{\circ}C$ HGHL HGHL 16 25 25 SUPPLY CURRENT (mA) SUPPLY CURRENT (mA) 15 LGHL 20 HGLL 20 GAIN (dB) 14 TA = +85°C 15 15 $T_A = +25^{\circ}C$ HGLL 13 FM 10 10 12 5 5 11 0 0 10 100 -50 0 50 100 -50 0 50 4 6 8 10 12 14 16 TEMPERATURE (°C) LNA CURRENT (mA) TEMPERATURE (°C) **PCS-BAND LNA GAIN CELLULAR-BAND HGHL LNA GAIN CELLULAR-BAND LNA GAIN** vs. CURRENT vs. FREQUENCY vs. FREQUENCY 17 18 20 $T_A = -40^{\circ}C$ 16 HGHL HGHL 17 15 15 HGLL, FM 14 16 HGLI 13 10 GAIN (dB) GAIN (dB) GAIN (dB) 12 15 11 5 =+25°C TA = +85°C 14 10 9 0 13 LGHL 8 7 12 -5 1900 1920 4 6 8 10 12 14 16 18 20 850 860 870 880 890 900 1940 1960 1980 2000 FREQUENCY (MHz) FREQUENCY (MHz) LNA CURRENT (mA) **PCS-BAND HGHL LNA IIP3 PCS-BAND HGHL LNA NOISE FIGURE CELLULAR-BAND HGHL LNA IIP3** vs. CURRENT vs. CURRENT vs. FREQUENCY 10 2.0 14 TA = -40°0 $T_A = -40^\circ C$ $T_A = +25^{\circ}C$ 9 1.9 12 8 1.8 NOISE FIGURE (dB) 10 1.7 7 $T_A = +85^{\circ}C$ 4mA $T_A = +25^{\circ}C$ IIP3 (dBm) IIP3 (dBm) 6 1.6 8 8.4mA $T_A = +85^{\circ}C$ 5 1.5 6 Y 4 1.4 4 3 1.3 15mA 2 2 1.2 4 5 6 7 8 9 4 6 8 10 12 14 16 1900 1920 1940 1960 1980 2000 LNA CURRENT (mA) FREQUENCY (MHz) LNA CURRENT (mA)



MAX2338

Typical Operating Characteristics (continued)

 $(T_A = +25^{\circ}C, unless otherwise noted.)$









_____Pin Description

PIN	NAME	FUNCTION
1	RLNA	LNA Bias–Setting Resistor Connection. For nominal bias, connect a $24k\Omega$ resistor to ground. The value of this resistor sets the bias current for HGHL LNAs.
2	PLNAIN	High-Band RF Input. Requires a blocking capacitor which may be used as part of the input matching network.
3, 8, 11, 18, 24, 25, 27, Exposed Paddle	GND	Ground Reference for RF, DC and Logic Inputs. Solder the exposed paddle evenly to the circuit board ground plane.
4	CLNAIN	Low-Band RF Input. Requires a blocking capacitor which may be used as part of the input matching network.
5	BAND	Band-Select Logic Input. LOW selects high-band (PCS), HIGH selects low-band (cellular).
6	LIN	Linearity-Select Logic Input. See Detailed Description for control modes.
7	GAIN	Gain-Select Logic Input. See Detailed Description for control modes.
9	LO/2	LO Divider-Select Input. LOW disables LO divider, HIGH selects divider in cellular and FM modes. See <i>Detailed Description</i> for control modes.
10	LOIN	LO Input Port. Requires an external DC blocking capacitor.
12	PLOOUT	PCS LO Buffer Output Port. Internally matched to 100Ω (nominal). Does not require a blocking capacitor.
13	CLOOUT	Cell LO Buffer Output Port. Internally matched to 100Ω (nominal). Does not require a blocking capacitor. The output frequency is one half LOIN when LO/2 is floating or HIGH, and equal to LOIN when LO/2 is LOW.
14	NC	No Connection
15	FMOUT	FM Mixer Output Port. Requires pullup inductor and DC blocking capacitor, which may be used as part of the output matching network.
16	V _{CC}	Power Supply Pin. Bypass with capacitor as close to the pin as possible.
17	BUFFEN	LO Output Buffer Enable. Drive BUFFEN HIGH to power up the LO output buffer associated with the selected band.
19, 20	IF-, IF+	Mixer Differential Outputs. Require pullup inductors and series capacitors which can be used as part of the output matching network.
21	RBIAS	Bias Setting Resistor Connection. For nominal bias, connect a $24k\Omega$ resistor to ground. The value of this resistor sets current for all blocks except HGHL LNA.
22	CMIXIN	Low-Band Mixer Input. Requires a blocking capacitor which may be used as part of the input matching network.
23	PMIXIN	High-Band Mixer Input. Requires a blocking capacitor which may be used as part of the input matching network.
26	PLNAOUT	High-Band LNA Output Port. Connect a pullup inductor to V_{CC} and an external series blocking capacitor which may be used as a part of the output matching network.
28	CLNAOUT	Low-Band LNA Output Port. Connect a pullup inductor to V_{CC} and an external series blocking capacitor which may be used as a part of the output matching network.

Detailed Description

The MAX2338 consists of cellular band and PCS band (LNAs) and mixers. The IC also consists of a local oscillator (LO) divider and LO buffers for cellular and PCS bands.

Low-Noise Amplifiers

The MAX2338 LNAs' gain and linearity are switched by the GAIN and LIN input, respectively. The PCS band LNA has two operational modes: high-gain high-linearity (HGHL) and high-gain low-linearity (HGLL). The cellular band LNA has three operational in modes: HGHL, HGLL, and low-gain high-linearity (LGHL) modes. The table in the *Operational Modes* section shows the pin settings for BAND, GAIN, and LIN for various operating modes. Use HGHL mode when extra high linearity is required for cross-modulation suppression, HGLL mode when the transmitter is off and cross-modulation is not a concern, and LGHL mode when receiving large signals.

Downconverter

The downconverters in these devices are double balanced mixers. The PCS band mixer and digital cellular band mixer share the same IF output ports. The cellular FM band mixer has its own IF output to feed to a different filter. When the linearity requirement is high, the LIN control input increases the current in the downconverter. The downconverter requires a DC blocking capacitor at the input and output, and a pullup inductor at the output. The DC blocking capacitors can be designed to be part of the matching circuits. The table in the *Operational Modes* section shows the settings for BAND, GAIN, and LIN for various operating modes.

LO Output Buffers

There are two LO output buffers: cellular and PCS. The inputs are tied together and internally matched to 50Ω . The outputs of the PCS and cellular buffers are brought out separately. The outputs of the buffers are internally matched and include a DC blocking capacitor.

LO Divider

The MAX2338 includes an LO divider circuit which enables a single VCO for both cellular and PCS bands. The LO/2 logic input turns the divider on or off in the cellular band.

	FUNCTION							CONTROL PIN					
MODES	BAND (H/L)	LOX1	LO /2	HGHL Amp	HGLL Amp	LGHL Amp	CDMA HL Mixer	CDMA LL Mixer	FM Mixer	BAND	GAIN	LIN	LO/2
PCS Band, High-Gain, High-Linearity (HGHL)	Н	~		~			~			0	1	1	Х
PCS Band, High-Gain, Low-Linearty (Idle Mode) (HGLL)	Н	1			1			~		0	1	0	Х
Undefined	—	—	—	—	—	—	—	—	—	0	0	1	Х
Cellular Band CDMA, High-Gain, High-Linearity (HGHL)	L		1	1			1			1	1	1	1
Cellular Band CDMA, High-Gain, Low-Linearity (Idle Mode) (HGLL)	L		~		~			1		1	1	0	1
Cellular Band, CDMA, Low-Gain	L		1			1	1			1	0	1	1
Cellular Band, FM Mode	L		1		1				1	1	0	0	1
Cellular Band CDMA, High-Gain, High-Linearity (HGHL)	L	1		1			1			1	1	1	0
Cellular Band CDMA, High-Gain, Low-Linearity (Idle Mode) (HGLL)	L	1			1			1		1	1	0	0
Cellular Band, CDMA, Low-Gain	L	1				1	1			1	0	1	0
Cellular Band, FM Mode	L	1			1				~	1	0	0	0
Shutdown										0	0	0	Х

Table 1. Operational Modes



Operational Modes

The various operating modes are controlled by the logic inputs BAND, GAIN, LIN, and LO/2. Table 1 shows the pin settings for the various operating modes.

_Applications Information

Cascaded LNA/Mixer Performance

The LNA and mixer design optimizes cascaded performance in all gain and linearity modes. In HGHL mode both the LNA and mixer have a low noise figure, high gain, and high linearity. The LNA has high gain to minimize the noise contribution of the mixer, thus increasing the receiver's sensitivity, and the LNA has high linearity for cross-modulation suppression. The HGLL mode is used when the transmitter is off and cross-modulation is not a concern. In LGHL mode, the received signal is strong enough that linearity is the primary concern. The LNA gain is reduced for higher system linearity.

S-Parameters

Use the S-parameters listed in the following tables to design the RF matching circuits.

Table 2. MAX2338 Cellular Band LNA S-parameters High-Gain, High-Linearity Mode

FREQUENCY (MHz)	IS11	∠ S 11	 S21	∠ S21	IS12	∠S12	S22	∠S22
30	0.905	-5.4	0.145	-38	0.002	-55	0.98	-47
50	0.899	-8.1	0.467	-57	0.003	-126	0.94	-72
100	0.891	-15.1	1.34	-86	0.012	-174	0.96	-117
150	0.884	-21.8	2.2	-108	0.023	176	0.96	-144
200	0.874	-28.2	2.83	-127	0.027	165.8	0.95	-162
300	0.85	-41.6	3.77	-157.5	0.029	137	0.93	-172
400	0.818	-52.5	4.24	178.3	0.030	127	0.90	155
500	0.785	-63.5	4.44	155.4	0.036	112	0.94	129
600	0.75	-71.6	4.38	140	0.040	98	0.87	100
700	0.714	-79.8	4.16	125	0.048	90	0.84	78
800	0.683	-76.5	4.03	112.6	0.059	83.0	0.793	67.5
810	0.681	-77.0	4.01	111.2	0.060	82.8	0.798	66.5
820	0.677	-77.0	3.99	110.0	0.061	82.0	0.800	65.7
830	0.675	-78.0	3.97	108.5	0.061	80.9	0.799	65.0
840	0.670	-78.3	3.96	107.2	0.062	80.6	0.792	64.2
850	0.668	-78.8	3.93	106.4	0.063	79.2	0.782	63.4
860	0.665	-79.0	3.92	104.7	0.063	78.1	0.769	62.7
870	0.661	-79.5	3.91	103.4	0.063	77.2	0.753	61.8
880	0.660	-80.0	3.89	102.1	0.063	76.5	0.733	60.6
890	0.660	-80.4	3.87	100.8	0.063	75.4	0.710	59.4
900	0.653	-81.0	3.86	99.3	0.063	73.5	0.690	57.7
1000	0.614	-97.0	3.59	86.2	0.07	20	0.680	51.8
1250	0.547	-111	3.15	60.8	0.09	-13.2	0.650	37
1500	0.457	-131	2.93	34	0.109	-36	0.610	15.9
1750	0.310	-164	2.48	18	0.14	-62	0.580	-9.6
2000	0.320	166	2.1	-40	0.185	-98	0.490	-33
2500	0.300	141	1.62	-41	0.19	-150	0.360	-70
3000	0.310	122	1.29	-66	0.19	136	0.41	-64
3500	0.360	86	1.18	-88	0.2	90	0.500	-61
4000	0.360	10	1.14	-112	0.2	43	0.480	-50



Layout Considerations

Keep RF signal lines as short as possible to minimize losses and radiation. Use high Q components for the LNA input-matching circuit to achieve the lowest possible noise figure. At the digital mixer outputs, keep the differential signal lines together and of equal length to ensure signal balance. For best gain and noise performance, solder the exposed paddle evenly to the board ground plane.

Table 3. MAX2338 PCS Band LNA S-Parameters High-Gain, High-Linearity Mode

FREQUENCY (MHz)	S11	∠ S 11	 S21	∠ S21	IS12I	∠S12	S22	∠S22
30	0.890	-4.9	0.002	-95	0.001	-112	0.996	-48
50	0.883	-7.2	0.001	-60	0.001	-121	0.990	-73
100	0.872	-13.2	0.391	-81	0.002	-178	0.980	-114
200	0.841	-25	0.882	-112	0.007	171	0.970	-150
300	0.799	-35	1.42	-131	0.010	150	0.959	-166
400	0.778	-41	2.1	-153	0.02	125	0.947	-173
600	0.750	-62	2.15	-172	0.02	100	0.943	173
800	0.706	-75	2.2	162	0.025	80	0.944	151
1000	0.676	-85	2.45	150	0.029	65	0.919	133
1200	0.659	-94	2.59	142	0.032	42	0.879	115
1500	0.634	-108	3.03	134	0.036	31	0.824	94.4
1750	0.578	-110	3.58	126	0.038	19	0.780	81
1900	0.560	-90.8	3.64	120.6	0.04	11.8	0.740	61.7
1910	0.558	-91.0	3.64	119.6	0.04	9.06	0.738	60.7
1920	0.554	-91.4	3.64	118.9	0.04	8.8	0.733	59.6
1930	0.551	-91.7	3.63	118.2	0.04	6.7	0.729	58.5
1940	0.547	-92.2	3.63	117.7	0.04	5.3	0.725	57.4
1950	0.543	-92.2	3.63	117.0	0.04	4.87	0.720	56.1
1960	0.538	-92.4	3.63	116.5	0.04	4.1	0.716	55.0
1970	0.536	-92.5	3.61	115.9	0.04	1.8	0.716	53.6
1980	0.533	-92.9	3.60	115.2	0.04	1.5	0.711	52.3
1990	0.530	-93.0	3.59	114.7	0.04	0	0.707	50.9
2000	0.523	-93.4	3.57	113.0	0.04	-2.1	0.702	49.5
2250	0.347	-155	2.88	131	0.05	-32	0.518	24
2500	0.298	-158	2.71	172	0.05	-72	0.489	5
3000	0.273	-160	2.64	-165	0.06	-94	0.473	-18
4000	0.245	-170	2.03	-145	0.067	-120	0.425	-30

Table 4. MAX2338 Cellular Band Mixer Input S-Parameters High-Gain, High-Linearity Mode

FREQUENCY (MHz)	IS11I	∠S11
800	0.843	-67.5
810	0.843	-68.2
820	0.842	-68.8
830	0.842	-69.5
840	0.843	-70.2
850	0.843	-71.0
860	0.843	-71.6
870	0.843	-72.4
880	0.842	-73.0
890	0.841	-74.0
900	0.840	-75.0

Table 5. MAX2338 PCS Band Mixer Input S-Parameters High-Gain, High-Linearity Mode

FREQUENCY (MHz)	IS11I	∠S11
1900	0.762	-76.9
1910	0.759	-77.8
1920	0.755	-79.0
1930	0.752	-80.1
1940	0.747	-81.2
1950	0.744	-82.2
1960	0.741	-83.2
1970	0.739	-84.3
1980	0.734	-85.5
1990	0.730	-86.7
2000	0.723	87.9

_Typical Operating Circuit



Package Information

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For the latest package outline information, go to **www.maxim-ic.com/packages**.

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